



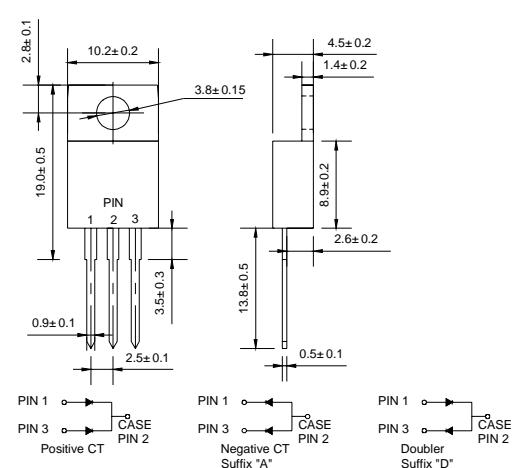
**VOLTAGE RANGE: 70 - 100 V**  
**CURRENT: 20 A**

## Features

- ◇ High surge capacity.
- ◇ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications.
- ◇ Metal silicon junction, majority carrier conduction.
- ◇ High current capacity, low forward voltage drop.
- ◇ Guard ring for over voltage protection.

## Mechanical Data

- ◇ Case: JEDEC TO-220AB, molded plastic body
- ◇ Terminals: Solderable per MIL-STD-750, Method 2026
- ◇ Polarity: As marked
- ◇ Weight: 0.071 ounce, 2.006 grams
- ◇ Position: Any



Dimensions in millimeters

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

		MBR2070CT	MBR2080CT	MBR2090CT	MBR20100CT	UNITS
Maximum recurrent peak reverse voltage	$V_{RRM}$	70	80	90	100	V
Maximum working peak reverse voltage	$V_{RWM}$	49	56	63	70	V
Maximum DC blocking voltage	$V_{DC}$	70	80	90	100	V
Maximum average forward total device rectified current @ $T_C = 133^\circ\text{C}$	$I_{F(AV)}$	20.0				A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	$I_{FSM}$	150.0				A
Maximum forward voltage per leg (NOTE 1) ( $I_F = 10\text{A}, T_C = 25^\circ\text{C}$ ) ( $I_F = 10\text{A}, T_C = 125^\circ\text{C}$ ) ( $I_F = 20\text{A}, T_C = 25^\circ\text{C}$ ) ( $I_F = 20\text{A}, T_C = 125^\circ\text{C}$ )	$V_F$	0.85 0.70 0.95 0.85				V
Maximum reverse current @ $T_A = 25^\circ\text{C}$ at rated DC blocking voltage @ $T_A = 125^\circ\text{C}$	$I_R$	0.1 6.0				mA
Maximum junction capacitance (NOTE2)	$C_T$	400				pF
Operating junction temperature range	$T_J$	- 55 ---- + 150				°C
Storage temperature range	$T_{STG}$	- 55 ---- + 175				°C

NOTE: 1. Pulse test: 300μs pulse width, 1% duty cycle.

2.  $V_R = 5\text{V}_\text{DC}$ , (test signal range 100KHz to 1MHz)



## Ratings AND Characteristic Curves

FIG.1 – FORWARD CURRENT DERATING CURVE

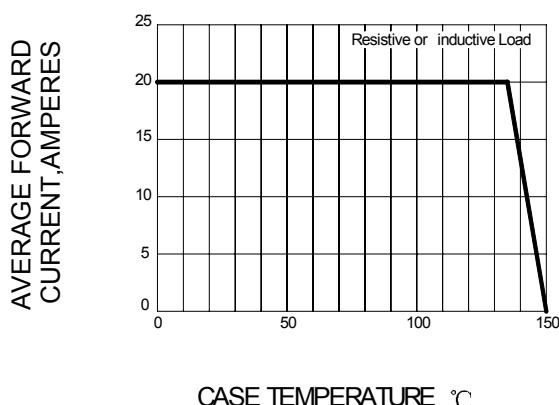


FIG.3 – TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS PER LEG

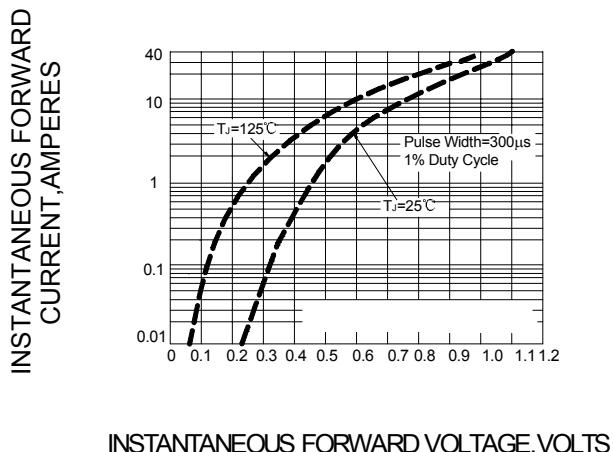


FIG.2 – MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT PER LEG

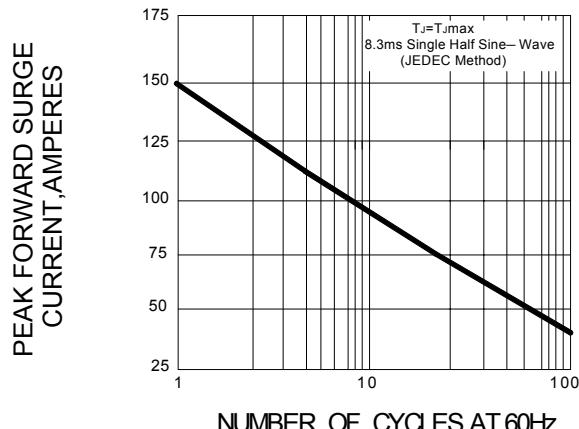


FIG.4 – TYPICAL REVERSE CHARACTERISTICS PER LEG

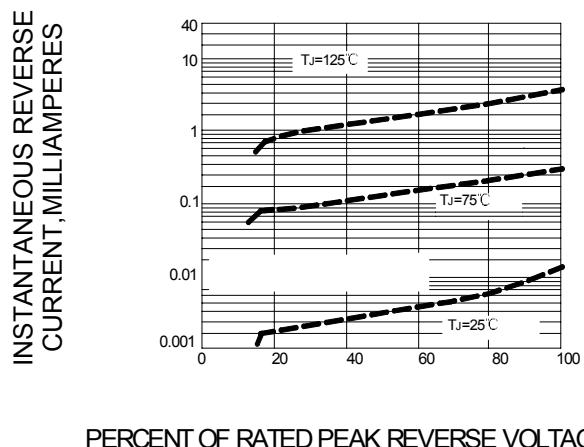
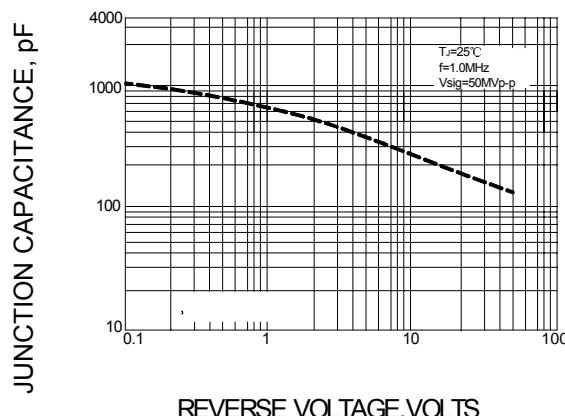


FIG.5-TYPICAL JUNCTION CAPACITANCE PER LEG



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